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26522 La Alameda Avenue, Suite 360  
Mission Viejo, California 92691  
tel: (949) 282-1000  
fax: (949) 282-1002

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Date: May 10, 2004

To: United States Patent and Trademark Office  
Examiner Luan C. Thai, Art Unit 2827

Fax: (703) 872-9306

Re: Application Serial No.: 10/618,273  
Filing Date: 7/11/2003; Inventor(s): Jeon, et al.  
Attorney Docket No.: 0180142

From: Farjami & Farjami LLP

Number of pages including the cover sheet: 6

Message:

Enclosed please find the Amendment and Response to the Office Action dated April 20, 2004.

Thank you.

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Attorney Docket No.: 0180142

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In re Application of: Jeon, et al.

Serial No.: 10/618,273

Filed: July 11, 2003

For: Method for Forming a Field Effect  
Transistor Having a High-K Gate  
Dielectric and Related Structure

Art Unit: 2827

Examiner: THAI, LUAN C.

**AMENDMENT AND RESPONSE TO OFFICE ACTION**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir/Madam:

This is in response to the Office Action dated April 20, 2004 in the above-referenced patent application. Please enter and consider the following amendments and remarks.